

Silicon Nanowires (SiNWs)

Catlog Number: BMAM-0028

• Description

High-aspect-ratio silicon nanowires that alleviate mechanical strain during lithiation, providing a path for electrons and high gravimetric capacity.

• Basic Information

Chemical Formula: Si

Appearance: Dark Brown Powder

D50 Particle Size: Length: 5-20 μm

Tap Density: $\geq 0.2 \text{ g/cm}^3$

BET Surface Area: 50 - 100 m^2/g

1st Discharge Capacity: $\geq 3200 \text{ mAh/g}$

1st Coulombic Efficiency: $\geq 80\%$

Carbon Content: N/A

Active Metal Content: Si: $\geq 99.9\%$

Ash Content: $\leq 0.05\%$

Moisture Content: $\leq 0.10\%$

pH Value: 6.0 - 7.0

Iron (Fe) Impurity: $\leq 15 \text{ ppm}$

True Density: 2.3 - 2.4 g/cm^3

Compaction Density: N/A

Crystal Structure: Crystalline

Surface Coating: Oxide layer

Magnetic Impurities: $\leq 20 \text{ ppb}$

Electronic Conductivity: $\sim 10^{-2} \text{ S/cm}$

Voltage Range: 0.01 - 1.5 V

Purity: $\geq 99.9\%$

Primary Application: High-capacity research

Thermal Stability: Moderate

Cycle Life: $\geq 500 \text{ cycles}$

 For Research or Industrial Raw Materials, Not For Personal Medical Use!